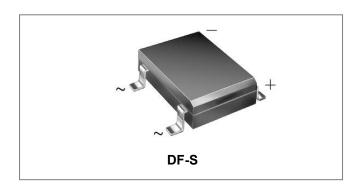






# DF150S-DF1510S

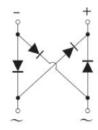
# Single-Phase 1.5A Surface Mount Glass Passivated Bridge Rectifiers



#### **Features**

- · Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



#### **Mechanical Data**

- Case: DF-S, molded plastic
- Terminals: plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting position: Any
- Lead Free: For RoHS / Lead Free Version,

#### Maximum Ratings @TA=25°C unless otherwise specified

Single Phase half wave 60Hz, resistive or inductive load. For capacitive load current derate by 20%.

Characteristic	Symbol	DF 150S	DF 151S	DF 152S	DF 154S	DF 156S	DF 158S	DF 1510S	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average Forward Output Current (Note 1) @ T <sub>A</sub> =40°C	I <sub>F(AV)</sub>	1.5						Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	55					A		

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# Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	DF 150S	DF 151S	DF 152S	DF 154S	DF 156S	DF 158S	DF 1510S	Units
Maximum Forward Voltage Drop* per Bridge Element @I <sub>F</sub> =1.5A, T <sub>J</sub> =25°C	V <sub>F</sub>				1.1				V
Peak Reverse Current* @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage* @T <sub>A</sub> = 125°C	I <sub>R</sub>				5 500				μA
Typical Junction Capacitance (Note 2)	CJ				25				pF

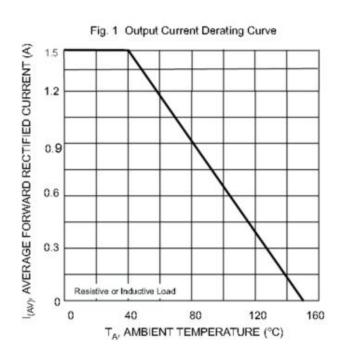
<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

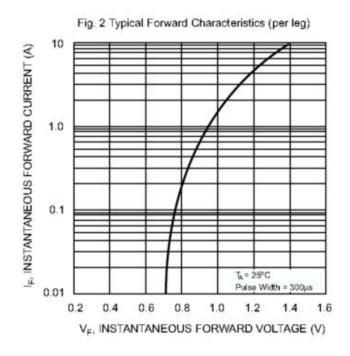
#### Thermal-Mechanical Specifications @TA=25°C unless otherwise specified

Characteristic	Symbol	DF 150S	DF 151S	DF 152S	DF 154S	DF 156S	DF 158S	DF 1510S	Units
Typical Thermal Resistance Junction to Ambient	R <sub>0JA</sub>				40				°C/W
Typical Thermal Resistance Junction to Lead					°C/W				
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to + 150			°C				

Note: 1. Mounted on glass epoxy PC board with 1.3mm<sup>2</sup> solder pad.

# **Ratings and Characteristics Curves**





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<sup>2.</sup> Measured at 1.0 MHZ and applied reverse voltage of 4.0 VDC

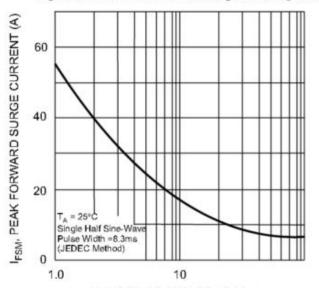


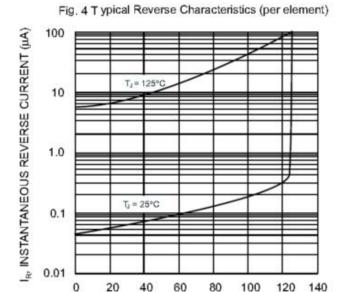




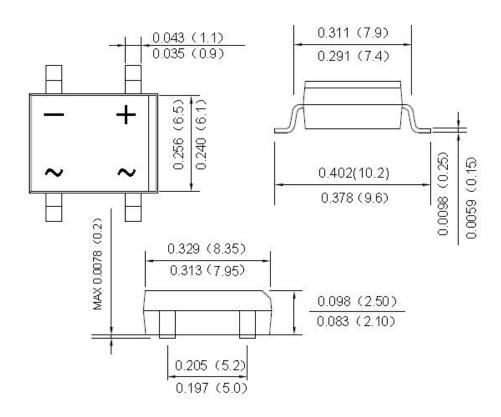


Fig. 3 Maximum Peak Forward Surge Current (per leg)





#### **Mechanical Dimensions DF-S(Inches/Millimeters)**



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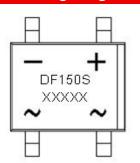


### **Ordering Information**

Device	Package	Shipping
DB150S THRU DB1510S	DB-S (Pb-Free)	1500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Marking Diagram**



Where XXXXX is YYWWL

 DB150S
 = Type Number

 YY
 = Year

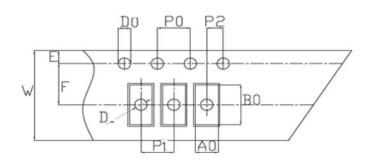
 WW
 = Week

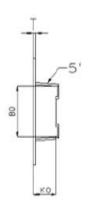
 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Carrier Tape Specification DB-S**





OVMDOL	Millimeters						
SYMBOL	Min.	Max.					
A0	8.65	8.95					
В0	10.31	10.51					
D0	1.50	1.60					
D1	1.40	1.60					
P0	3.90	4.10					
P1	11.90	12.10					
P2	1.90	2.10					
E	1.65	1.85					
K0	3.21	3.41					
F	7.40	7.60					
W	15.70	16.30					
Т	0.30	0.40					
10P0	39.80	40.20					



#### **DF150S THRU DF1510S**

#### Technical Data Data Sheet N0468, Rev. A





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